GLF72111 3A, Ultra-low Power I_QSmart[™] Load Switch with True Reverse Current Blocking



Product Brief

DESCRIPTION

The GLF72111 is an advanced technology fully integrated $I_{\Omega}Smart^{TM}$ load switch device with True Reverse Current Blocking (TRCB) technology and slew rate control of the output voltage.

The GLF72111 offers industry leading True Reverse Current Blocking (TRCB) performance, featuring an ultra-low threshold voltage. It minimizes reverse current flow in the event that the VOUT pin voltage exceeds the VIN voltage.

The GLF72111 has industry leading efficiency. It

features a R_{ON} as low as 29 m Ω typical at 5.5 V, reducing power loss during conduction. The device also features ultra-low shutdown current (I_{SD}) to reduce power loss and battery drain in the off state. When EN is pulled low, and the output is grounded, the GLF72111 can achieve an I_{SD} as low as 24 nA typical at 5.5 V.

The GLF72111 load switch device supports an industry leading wide input voltage range and helps to improve operating life and system robustness. Furthermore, one device can be used in multiple voltage rail applications which helps to simplify inventory management and reduces operating cost.

The GLF72111 load switch device is small, utilizing a chip scale package with 4 bumps in a 0.97 mm x 0.97 mm x 0.55 mm die size and a 0.5 mm pitch.

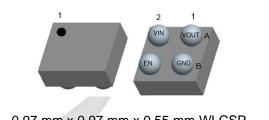
FEATURES

- True Reverse Current Blocking
- Ultra-Low I_Q : 1.4 uA Typ @ 5.5 V_{IN}
- Ultra-Low I_{SD}: 24 nA Typ @ 5.5 V_{IN}
- Low R_{ON} : 29 mΩ Typ @ 5.5V_{IN}
- I_{OUT} Max: 3 A
- Wide Input Range: 1.5 V to 5.5 V 6 Vabs max
- Controlled Rise Time: 1.2 ms at 3.3 $V_{\mbox{\scriptsize IN}}$
- Internal EN Pull-Down Resistor, REN
- Integrated Output Discharge Switch
- 0.97 mm x 0.97 mm x 0.55 mm Wafer Level Chip Scale Package

APPLICATIONS

- Mobile Devices
- Wearables
- Low Power Subsystems

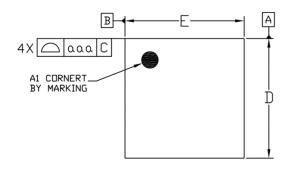
PACKAGE

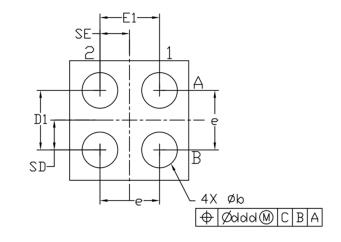


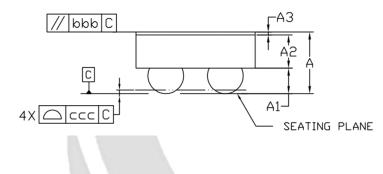
0.97 mm x 0.97 mm x 0.55 mm WLCSP



PACKAGE OUTLINE







Dimensional Ref.											
REF.	Min.	Nom.	Max.								
Α	0.500	0.550	0.600								
A1	0.225	0.250	0.275								
A2	0.255	0.255 0.275 0.30									
A3	0.020	0.030									
D	0.960	0.970	0.985								
E	0.960	0.970	0.985								
D1	0.450	0.500	0.550								
E1	0.450	0.500	0.550								
Ь	0.260	0.310	0.360								
е	0.500 BSC										
SD	0.250 BSC										
SE	0.250 BSC										
Tol. of Form&Position											
ааа	0.10										
ЬЬЬ	0.10										
ССС	0.05										
ddd		0.05									

Notes

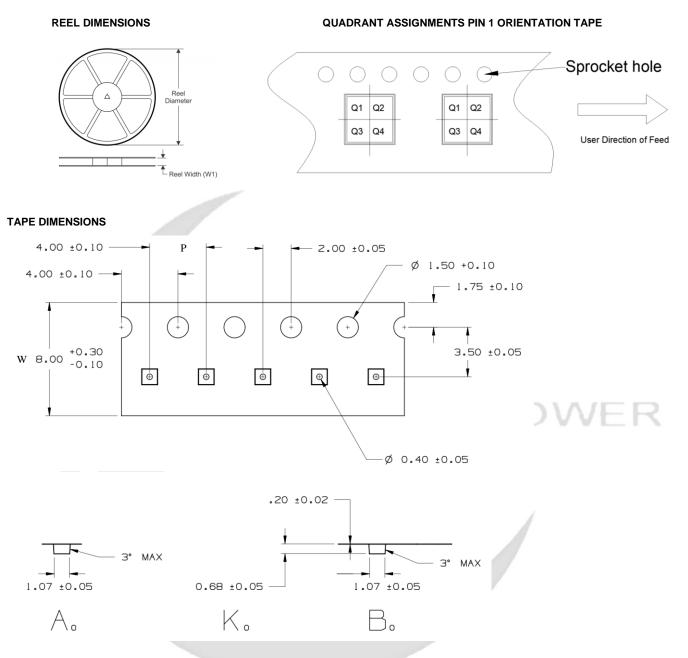
1. ALL DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGRESS)

2. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M-1994.

3. A3: BACKSIDE LAMINATION

TAPE AND REEL INFORMATION

INTEGRATED POWER



Device	Package	Pins	SPQ	Reel Diameter(mm)	Reel Width W1	A0	В0	KO	Ρ	w	Pin1
GLF72111	WLCSP	4	3000	180	9	1.07	1.07	0.68	4	8	Q1

Remark:

- A0: Dimension designed to accommodate the component width
- B0: Dimension designed to accommodate the component length
- C0: Dimension designed to accommodate the component thickness
- W: Overall width of the carrier tape
- P: Pitch between successive cavity centers